Vishay Semiconductors

High Performance Schottky Rectifier, 100 A





PowerTab[®]

PRODUCT SUMMARY				
Package	PowerTab [®]			
I _{F(AV)}	100 A			
V _R	30 V			
V _F at I _F	0.56 V			
I _{RM}	460 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	9 mJ			

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FEATURES

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
 COMPLIANT
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ030HF4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
1	Rectangular waveform	100	А			
I _{F(AV)}	T _C	106	°C			
V _{RRM}		30	V			
I _{FSM}	t _p = 5 μs sine	4500	А			
100 A _{pk} (typical)		0.49	V			
V _F	TJ	150	°C			
TJ	Range	-55 to +150	۵°			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-100BGQ030HF4	UNITS		
Maximum DC reverse voltage	V _R	30	N/		
Maximum working peak reverse voltage	V _{RWM}	50	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	DITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_C = 106 °C	100	А		
Maximum peak one cycle	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	4500	A	
non-repetitive surge current		10 ms sine or 6 ms rect. pulse		850		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 8 A, L = 1.12 mH		36	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 8		А		

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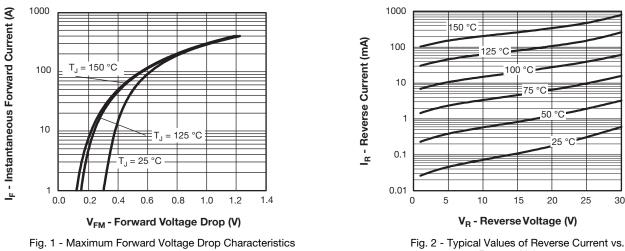
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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS
		50 A	T _{.1} = 25 °C	0.47	0.5	v
Forward valtage drep	V (1)	100 A	1j=25 C	0.56	0.63	
Forward voltage drop	V _{FM} ⁽¹⁾	50 A	T 150.00	0.36	0.4	
		100 A	T _J = 150 °C	0.49	0.56	
		T _J = 125 °C, V _R = 15 V		80	160	
Deverse leakers overent	I (1)	$T_{J} = 150 \text{ °C}, V_{R} = 30 \text{ V}$		800	1100	
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		0.6	2.4	mA
		T _J = 125 °C	V _R = Rated V _R	260	460	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz) 25 °C			00	pF
Typical series inductance	L _S	Measured from tab to mounting plane 3.5			nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/ ₄			V/µs	

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and temperature range	storage	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resis junction to case	tance,	R _{thJC}	DC operation	0.50	°C/W	
Typical thermal resistar case to heatsink	nce,	R _{thCS} Mounting surface, smooth and greased		0.30	0, W	
Approximate weight				5	g	
Approximate weight				0.18	oz.	
minimum				1.2 (10)	N · m	
Mounting torque max	maximum			2.4 (20)	(lbf · in)	
Marking device Case style PowerTab®		Case style PowerTab®	100BG	Q030H		



Reverse Voltage

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VS-100BGQ030HF4

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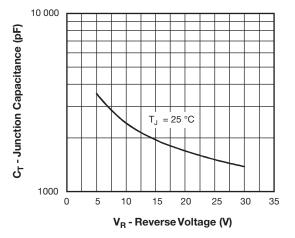


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

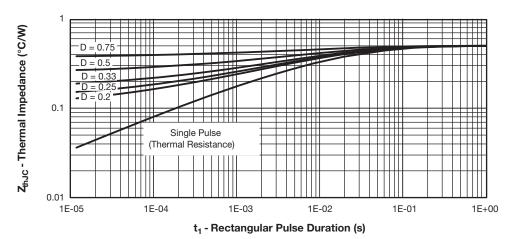
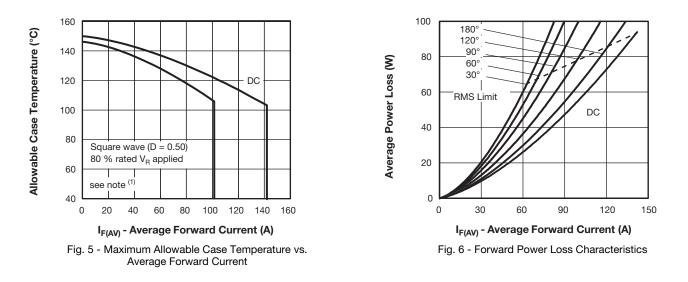


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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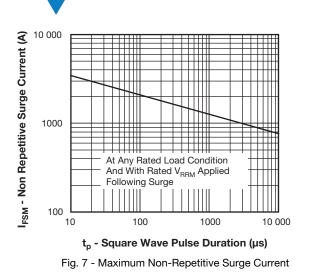
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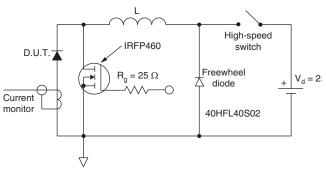
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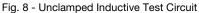
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Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC};$ Pd = Forward power loss = $I_{F(AV)} \ x \ V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = 80 \ \%$ rated V_R

ORDERING INFORMATION TABLE

Device code	VS-	100	BGQ	030	н	F4	
		2	3	4	5	6	I
	1 2 3	- Cur - Ess	hay Sem rent rati sential pa	ng (100 art numt	= 100 A per	<i>.</i>)	
	4 5 6	- H=	tage rati AEC-Q /ironmer	101 qua	lified		
	<u> </u>			0		otally le	ad (Pb)-fre

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-100BGQ030HF4	25	375	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS

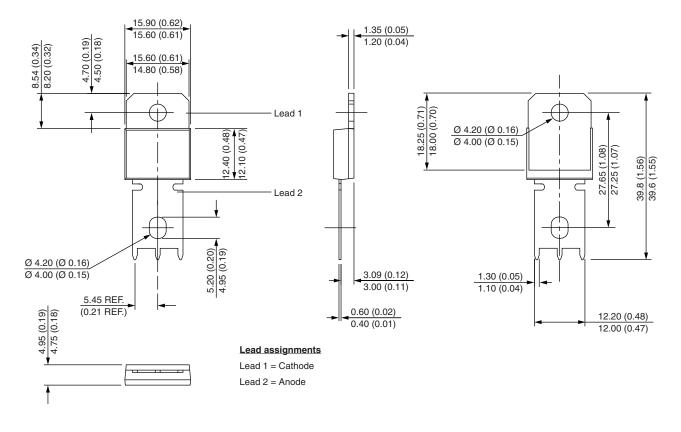
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			



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DIMENSIONS in millimeters (inches)





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